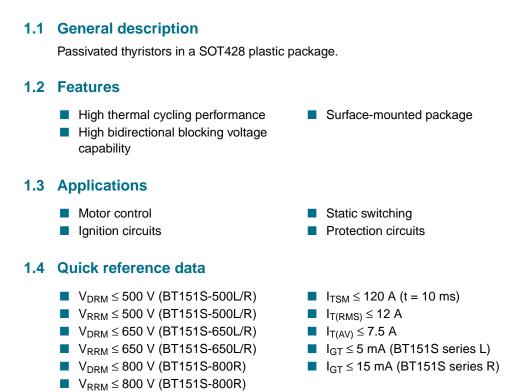


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Product data sheet

1. Product profile



2. Pinning information

Table 1.	Pinning		
Pin	Description	Simplified outline	Symbol
1	cathode (K)		
2	anode (A)	mb	А₽К
3	gate (G)		G sym037
mb	mounting base; connected to anode	L	
		SOT428 (DPAK)	



Thyristors

3. Ordering information

Table 2. Orderi	ng informatio	on					
Type number	Package	Package					
	Name	Description	Version				
BT151S-500L	DPAK	plastic single-ended surface-mounted package; 3 leads (one lead cropped)	SOT428				
BT151S-500R							
BT151S-650L							
BT151S-650R							
BT151S-800R							

4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

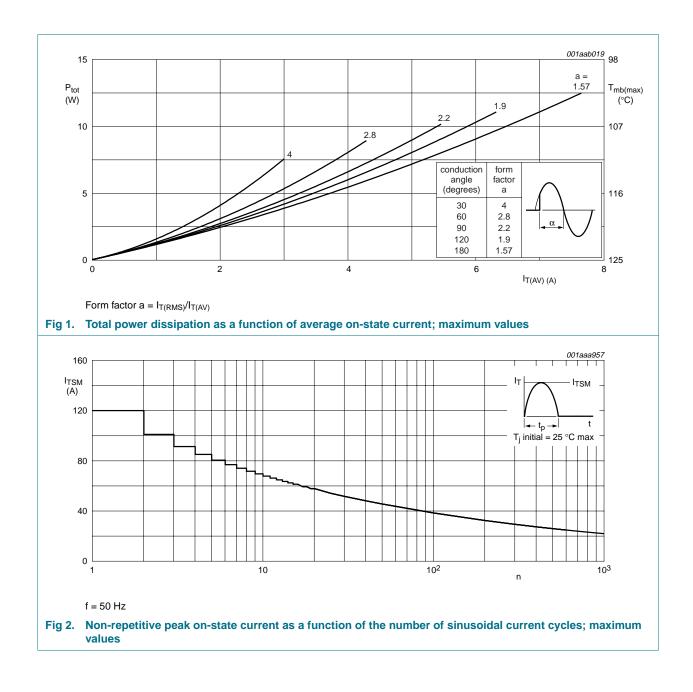
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage	BT151S-500L; BT151S-500R	<u>[1]</u> _	500	V
		BT151S-650L; BT151S-650R	<u>[1]</u> -	650	V
		BT151S-800R	-	800	V
V _{RRM}	repetitive peak reverse voltage	BT151S-500L; BT151S-500R	<u>[1]</u> _	500	V
		BT151S-650L; BT151S-650R	<u>[1]</u> _	650	V
		BT151S-800R	-	800	V
I _{T(AV)}	average on-state current	half sine wave; T _{mb} ≤ 103 °C; see <u>Figure 1</u>	-	7.5	А
I _{T(RMS)}	RMS on-state current	all conduction angles; see Figure 4 and $\frac{5}{2}$	-	12	А
I _{TSM}	non-repetitive peak on-state current	half sine wave; $T_j = 25 \text{ °C}$ prior to surge; see Figure 2 and 3			
		t = 10 ms	-	120	А
		t = 8.3 ms	-	132	А
l ² t	I ² t for fusing	t = 10 ms	-	72	A ² s
dl _T /dt	rate of rise of on-state current	I _{TM} = 20 A; I _G = 50 mA; dI _G /dt = 50 mA/μs	-	50	A/μs
I _{GM}	peak gate current		-	2	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	+150	°C
T _i	junction temperature		-	125	°C

 Although not recommended, off-state voltages up to 800 V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15A/µs.

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Product data sheet

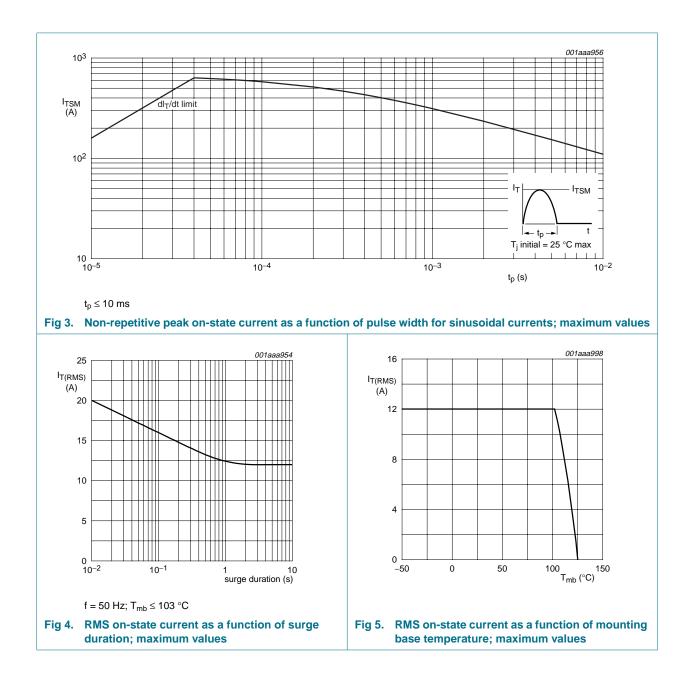
BT151S series L and R

Thyristors



BT151S series L and R

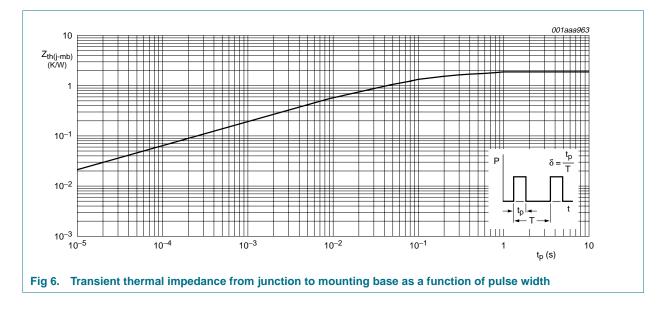
Thyristors



Thyristors

5. Thermal characteristics

Table 4.	Thermal characteristics						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
R _{th(j-mb)}	thermal resistance from junction to mounting base	see <u>Figure 6</u>	-	-	1.8	K/W	
R _{th(j-a)}	thermal resistance from junction to ambient	mounted on an FR4 printed-circuit board; see <u>Figure 14</u>	-	75	-	K/W	



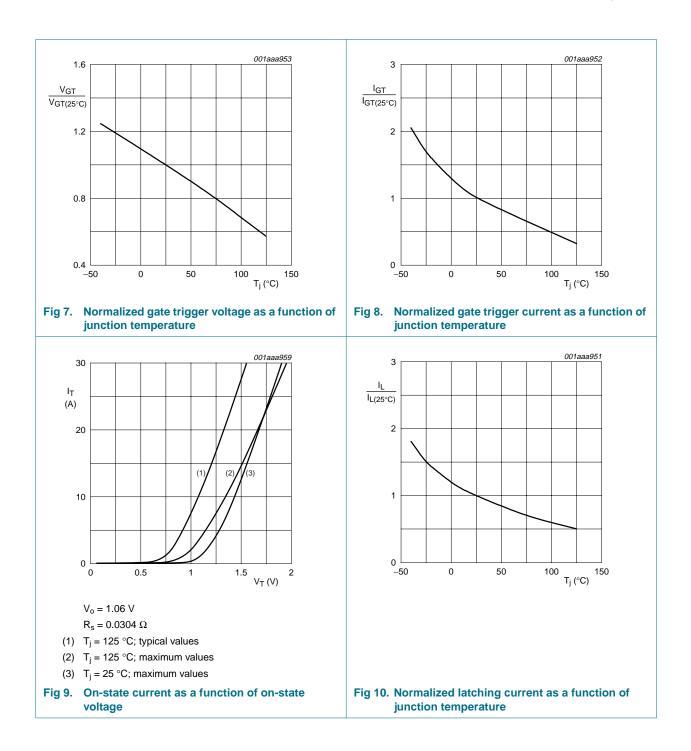
6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 100 \text{ mA}; \text{ see } \frac{\text{Figure 8}}{\text{Figure 8}}$				
		BT151S-500L	-	2	5	mA
		BT151S-500R	-	2	15	mA
		BT151S-650L	-	2	5	mA
		BT151S-650R	-	2	15	mA
		BT151S-800R	-	2	15	mA
IL	latching current	V _D = 12 V; I _{GT} = 100 mA; see <u>Figure 10</u>	-	10	40	mA
I _H	holding current	V _D = 12 V; I _{GT} = 100 mA; see <u>Figure 11</u>	-	7	20	mA
V _T	on-state voltage	I _T = 23 A; see <u>Figure 9</u>	-	1.4	1.75	V
V _{GT}	gate trigger voltage	$I_T = 100 \text{ mA}; V_D = 12 \text{ V}; \text{ see } \frac{\text{Figure 7}}{\text{Figure 7}}$	-	0.6	1.5	V
		$ I_T = 100 \text{ mA}; V_D = V_{DRM(max)}; $	0.25	0.4	-	V
I _D	off-state current	$V_D = V_{DRM(max)}; T_j = 125 \ ^{\circ}C$	-	0.1	0.5	mA
I _R	reverse current	$V_R = V_{RRM(max)}; T_j = 125 \ ^{\circ}C$	-	0.1	0.5	mA
Dynamic o	characteristics					
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 0.67 \times V_{DRM(max)}$; $T_j = 125 \text{ °C}$; exponential waveform; see Figure 12				
		R _{GK} = 100 Ω	200	1000	-	V/µs
		gate open circuit	50	130	-	V/µs
t _{gt}	gate-controlled turn-on time	$\begin{split} I_{TM} &= 40 \text{ A}; V_D = V_{DRM(max)}; \\ I_G &= 100 \text{ mA}; dI_G/dt = 5 A/\mu \text{s} \end{split}$	-	2	-	μs
tq	commutated turn-off time		-	70	-	μs

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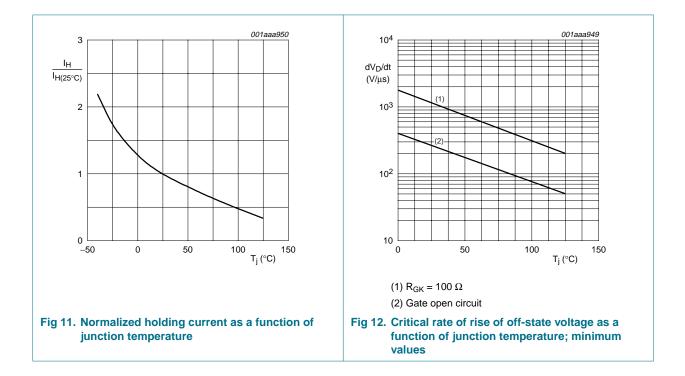


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7. Package outline

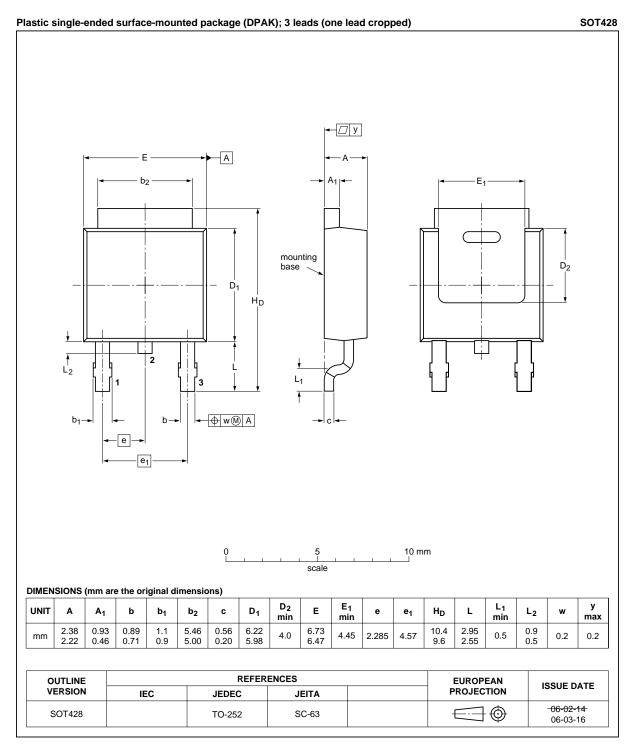


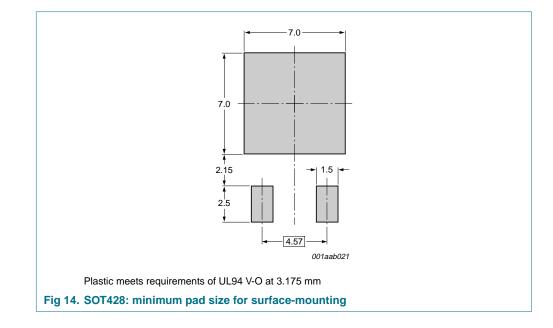
Fig 13. Package outline SOT428 (DPAK)

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Product data sheet

Thyristors

8. Mounting



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Thyristors

9. Revision history

Table 6. Revision his	tory					
Document ID	Release date	Data sheet status	Change notice	Supersedes		
BT151S_SER_L_R_5	20061009	Product data sheet	-	BT151S_SERIES_4		
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 					
	 Legal texts 	have been adapted to the ne	w company name whe	ere appropriate.		
	 Added type 	numbers BT151S-500L and	BT151S-650L			
BT151S_SERIES_4 (9397 750 13161)	20040609	Product specification	-	BT151S_SERIES_3		
BT151S_SERIES_3	20020101	Product specification	-	BT151S_SERIES_2		
BT151S_SERIES_2	19990601	Product specification	-	BT151S_SERIES_1		
BT151S_SERIES_1	19970901	Product specification	-	-		

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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